NSN 5962-01-360-1550

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View Online at https://aerobasegroup.com/nsn/5962-01-360-1550

Body Length:	
0.358 inches	
Body Width:	
0.310 inches	
Body Height:	
0.100 inches	
Maximum Power Dissipation Rating:	
303.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Burn in and bipolar and monolithic and programmed	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Leadless flat pack	
Output Logic Form:	
Bipolar metal-oxide semiconductor	
Input Circuit Pattern:	
16 input	
Case Outline Source And Designator:	
C-2 mil-m-38510	
Current Rating Per Characteristic:	
1.00 milliamperes input	
Terminal Surface Treatment:	
Solder	
Product Name:	
Microcircuits, digital, bipolar, programmable logic, monolithic silicon	
Voltage Rating And Type Per Characteristic:	
-0.5 volts power source and 7.0 volts power source	
Memory Device Type:	
Pal	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).	
Terminal Type And Quantity:	
20 leadless	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

No

Fiig:

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